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प्लाज़मा अनुसंधान संस्थान INSTITUTE FOR PLASMA RESEARCH परमाणु ऊर्जा विभाग, भारत सरकार का एक सहायता



प्राप्त संस्थान

An Aided Institute of Department of Atomic Energy, Government of India

इन्दिरा प्ल के पास, भाट, गांधीनगर - 382 428 भारत

दूरभाष: (079) 2396 2020/2021/2028

फैक्स: 91-079-23962277

वेब: www.ipr.res.in

NEAR INDIRA BRIDGE, BHAT

DIST. GANDHINAGAR - 382 428 (INDIA) Phone: (079) 2396 2020/2021/2028

Fax : 91-079-23962277

Web : www.ipr.res.in

ENQUIRY

ENQUIRY NO : IPR/EQL/19-20/146

Date : 09-07-2019

Due on : 01-08-2019 by 1:00 PM IST

Please send your offer in sealed envelope specifying Enquiry No, Date & Due Date, ALONG WITH your credentials for the following items:

Important Note:

Please note that e-mail quotations are not acceptable however you may send your queries (if any) to localpurchase@ipr.res.in

Please ensure your sealed quotation reaches this office not later than above mentioned due date and time.

Kindly go through the following documents properly before quoting which are available on the IPR web portal i.e., http://www.ipr.res.in/documents/tender_terms.html / attached herewith.

- 1) Instructions to the bidders & Terms and conditions (refer Form No: IPR-LP-01.V4)
- 2) Bidding format

GST for Goods and Services (IGST/CGST/SGST TAX BENEFITS): Please refer clause no: 8 of Form No: IPR-LP-01.V4

QUOTATION SHOULD BE ADDRESSED TO PURCHASE OFFICER ONLY

Sr No	Description	Quantity
1	4 inch prime grade silicon wafer	25.0 Nos.
2	6 inch prime grade silicon wafer	25.0 Nos.

Note: Note: (1) Unsigned quotations are not acceptable.

Quotation should be submitted duly signed on ALL PAGES

invariably

(2) TDS as per CGST Act: As per provisions of section No. 51 of the CGST Act 2017, TDS @ 2% (IGST 2% or CGST 1% and SGST 1%) will be deducted while making payment to the suppliers where total value of orders/contracts/work orders exceeds Rs. 2.5 Lakhs, in the event of order in Indian Rupees delivery time:- 04 months

Encl: As Per Attachment

Sd/-

Mr. D. Ramesh Purchase Officer-II

Information to Vendors: We are working towards a single platform for our future requirement. Hence, please refer IPR website i.e, http://www.ipr.res.in/documents/tenderseng.html for our future requirement.

Compliance Sheet

Sr. No.	IPR Specification	IPR Requirement	Vendor
1	4 Inch Silicon wafer		Diagrees C 11s b
	a) Grade	a) Prime	Thickness 400 50
	b) Diameter	b) 4 inch	silyiik. oneruk
	c) Thickness	c) 400-600 µm	Orientation gonates (10 p.
***	d) Surface	d) Single side polished	lar bod : food sa
	e) Orientation	e) <100>	
	f) Type	f) Intrinsic/Undoped	vitevi ganille duri è
70			eroiet Peiore
2	6 Inch Silicon wafer		Diameter Stamet
	a) Grade	a) Prime	finckness 400 to
	b) Diameter	b) 6 inch	Surface Single
1	c) Thickness	c) 500-700 µm	Orientation : <100>
4	d) Surface	d) Single side polished	agyT
	e) Orientation	e) <100>	
	f) Type	f) Intrinsic/Undoped	

Specification of Silicon Wafer

4 inch silicon wafer:

Grade

: Prime

Diameter

: 4 Inch

Thickness

: 400-600 µm

Surface

: Single side polished

Orientation

: <100>

Type

: Intrinsic/Undoped

6 inch silicon wafer:

Grade

: Prime

Diameter

: 6 Inch

Thickness

: 500-700 μm

Surface

: Single side polished

Orientation

: <100>

Type

: Intrinsic/Undoped